

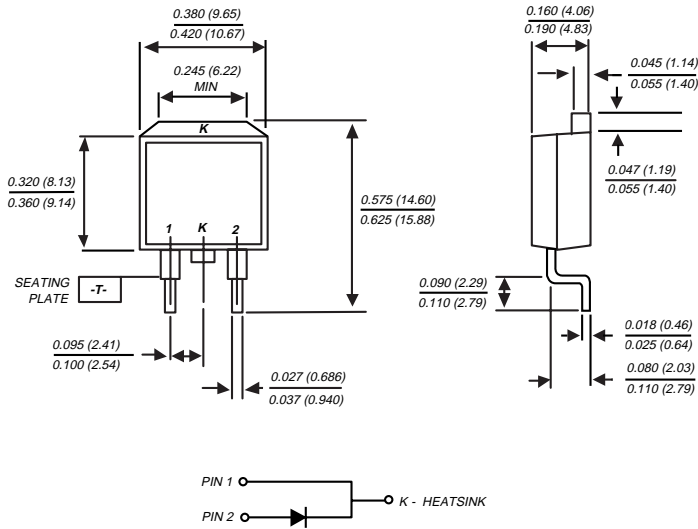
MBRB1035 THRU MBRB1060

SCHOTTKY RECTIFIER

Reverse Voltage - 35 to 60 Volts

Forward Current - 10.0 Amperes

TO-263AB



Dimensions in inches and (millimeters)

FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guardring for overvoltage protection
- ◆ High temperature soldering in accordance with CECC 802 / Reflow guaranteed



MECHANICAL DATA

Case: JEDEC TO-263AB molded plastic body
Terminals: Leads solderable per MIL-STD-750, Method 2026
Polarity: As marked
Mounting Position: Any
Weight: 0.08 ounces, 2.24 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	MBRB1035	MBRB1045	MBRB1050	MBRB1060	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	Volts
Maximum working peak reverse voltage	V _{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage	V _{DC}	35	45	50	60	Volts
Maximum average forward rectified current (SEE FIG. 1)	I _(AV)	10.0				Amps
Peak repetitive forward current at T _C =135°C (square wave 20 KHz)	I _{FRM}	20.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	150.0				Amps
Peak repetitive reverse surge current (NOTE 1)	I _{RRM}	1.0		0.5		Amps
Voltage rate of change (rated V _R)	dv/dt	10,000				V/μs
Maximum instantaneous forward voltage at (NOTE 2)	V _F	-		0.80		Volts
I _F =10A, T _C =25°C		0.57		0.70		
I _F =10A, T _C =125°C		0.84		0.95		
I _F =20A, T _C =25°C		0.72		0.85		
Maximum instantaneous reverse current at rated DC blocking voltage	I _R	0.10		15.0		mA
T _C = 25°C (NOTE 2) T _C =125°C		15.0				
Maximum thermal resistance, junction to case	R _{θJC}	2.0				°C/W
Operating junction temperature range	T _J	-65 to +150				°C
Storage temperature range	T _{STG}	-65 to +175				°C

NOTES:

- (1) 2.0μs pulse width, f=1.0 KHz
 (2) Pulse test: 300μs pulse width, 1% duty cycle

RATINGS AND CHARACTERISTIC CURVES MBRB1035 THRU MBRB1060

